

N-channel 30 V 3.3 mΩ logic level MOSFET in D2PAK Rev. 1 — 22 March 2012 Product

Product data sheet

Product profile 1.

1.1 General description

Logic level N-channel MOSFET in D2PAK package qualified to 175 °C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for logic level gate drive sources

1.3 Applications

- DC-to-DC converters
- Load switching

- Motor control
- Server power supplies

1.4 Quick reference data

Table 1.	Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	30	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; see <u>Figure 1</u>	<u>[1]</u>	-	-	100	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>		-	-	114	W
Tj	junction temperature			-55	-	175	°C
Static cha	aracteristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 100 °C; see <u>Figure 12</u> ; see <u>Figure 13</u>		-	3.91	4.6	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; see <u>Figure 13</u>		-	2.79	3.3	mΩ
Dynamic	characteristics						
Q _{GD}	gate-drain charge	V_{GS} = 4.5 V; I_{D} = 25 A; V_{DS} = 15 V;		-	8	-	nC
Q _{G(tot)}	total gate charge	see Figure 14; see Figure 15		-	31	-	nC
	e ruggedness						
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$ \begin{array}{l} V_{GS} = 10 \text{ V}; T_{j(\text{init})} = 25 \text{ °C}; \\ I_{D} = 100 \text{ A}; V_{sup} \leq 30 \text{ V}; \text{R}_{GS} = 50 \Omega; \\ \text{unclamped} \end{array} $		-	-	200	mJ

[1] Continuous current is limited by package.

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2. Pinning information

Table 2.	Pinning	information				
Pin	Symbol	Description	Simplified outline	Graphic symbol		
1	G	gate		_		
2	D	drain ^[1]	mb			
3	S	source				
mb	D mounting base; connected to drai	mounting base; connected to drain		mbb076 S		
			SOT404 (D2PAK)			

[1] it is not possible to make connection to pin 2

3. Ordering information

Table 3. Ordering information Type number Package Name Description Version PSMN3R4-30BL D2PAK plastic single-ended surface-mounted package (D2PAK); 3 leads SOT404 (one lead cropped)

4. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN3R4-30BL	PSMN3R4-30BL

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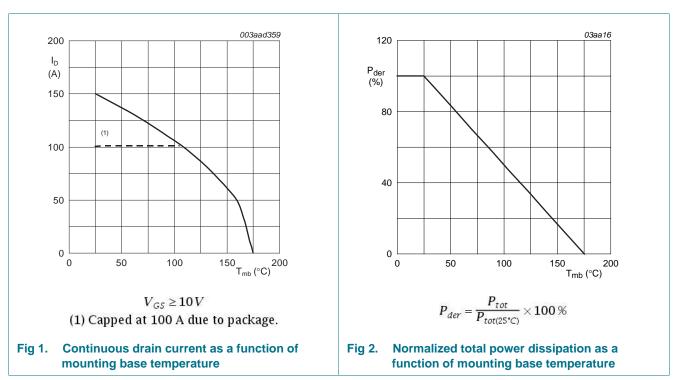
5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

	Min	Max	Unit
	-	30	V
	-	30	V
	-20	20	V
<u>[1]</u>	-	100	А
<u>[1]</u>	-	100	А
	-	609	А
	-	114	W
	-55	175	°C
	-55	175	°C
	-	260	°C
<u>[1]</u>	-	100	А
	-	609	А
	-	200	mJ
		-	- 200

[1] Continuous current is limited by package.



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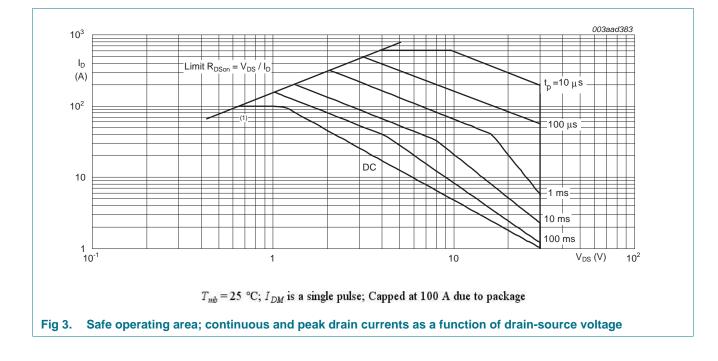


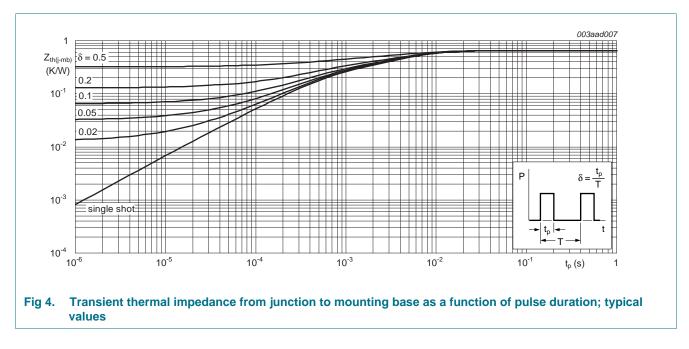
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6. Thermal characteristics

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Table 6.	I nermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see Figure 4	-	0.65	1	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	Minimum foot print; mounted on a printed circuit board	-	50	-	K/W



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7. Characteristics

Table 7. Characteristics

Tested to JEDEC standards where applicable.

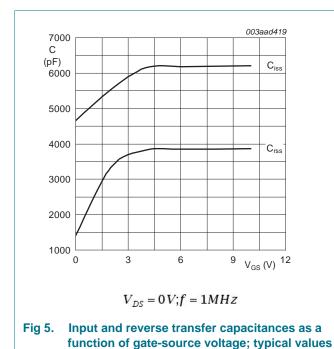
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics					
V _{(BR)DSS} drain-source breakdown vo		$I_D = 250 \ \mu A; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^{\circ}C$	30	-	-	V
		$I_D = 250 \ \mu A; \ V_{GS} = 0 \ V; \ T_j = -55 \ ^\circ C$	27	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ see <u>Figure 10</u> ; see <u>Figure 11</u>	1.3	1.7	2.15	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ see Figure 11	0.5	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ see <u>Figure 11</u>	-	-	2.45	V
I _{DSS}	drain leakage current	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	0.3	5	μA
		$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 125 \text{ °C}$	-	-	100	μA
I _{GSS}	gate leakage current	V_{GS} = 16 V; V_{DS} = 0 V; T_j = 25 °C	-	10	100	nA
		V_{GS} = -16 V; V_{DS} = 0 V; T_j = 25 °C	-	10	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; see <u>Figure 12</u> ; see <u>Figure 13</u>	-	5.3	6.2	mΩ
		V_{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; see <u>Figure 13</u>	-	3.27	3.8	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 100 °C; see <u>Figure 12</u> ; see <u>Figure 13</u>	-	3.91	4.6	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; see <u>Figure 13</u>	-	2.79	3.3	mΩ
R _G	gate resistance	f = 1 MHz	-	1	-	Ω
Dynamic c	haracteristics					
Q _{G(tot)}	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 10 \text{ V};$ see Figure 14; see Figure 15	-	64	-	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}$	-	58	-	nC
		$I_D = 25 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 4.5 \text{ V};$	-	31	-	nC
Q _{GS}	gate-source charge	see Figure 14; see Figure 15	-	12	-	nC
Q _{GS(th)}	pre-threshold gate-source charge		-	6.2	-	nC
Q _{GS(th-pl)}	post-threshold gate-source charge		-	5.8	-	nC
Q _{GD}	gate-drain charge		-	8	-	nC
V _{GS(pl)}	gate-source plateau voltage	$I_D = 25 \text{ A}; V_{DS} = 15 \text{ V}; \text{ see } \frac{\text{Figure } 14}{\text{Figure } 15};$	-	2.8	-	V
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz;	-	3907	-	pF
C _{oss}	output capacitance	T _j = 25 °C; see <u>Figure 16</u>	-	822	-	pF
C _{rss}	reverse transfer capacitance		-	356	-	pF

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Table 7. Characteristics ...continued

Tested to JEDEC standards where applicable.

		1				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{d(on)}	turn-on delay time	$\label{eq:VDS} \begin{array}{l} V_{DS} = 15 \; V; \; R_{L} = 0.5 \; \Omega; \; V_{GS} = 4.5 \; V; \\ R_{G(ext)} = 4.7 \; \Omega \end{array}$	-	40	-	ns
t _r	rise time		-	73	-	ns
t _{d(off)}	turn-off delay time			59	-	ns
t _f	fall time			28	-	ns
Source-dr	ain diode					
V_{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; see <u>Figure 17</u>	-	0.7	1.2	V
t _{rr}	reverse recovery time	I _S = 25 A; dI _S /dt = -100 A/µs;	-	36	-	ns
Q _r	recovered charge	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}$		28	-	nC



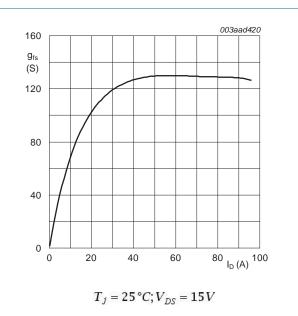
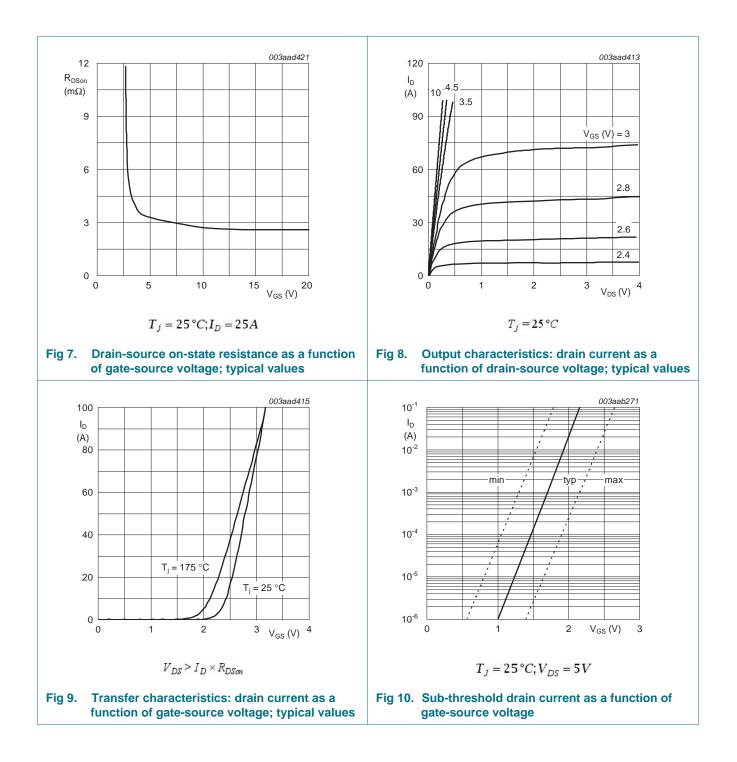


Fig 6. Forward transconductance as a function of drain current; typical values

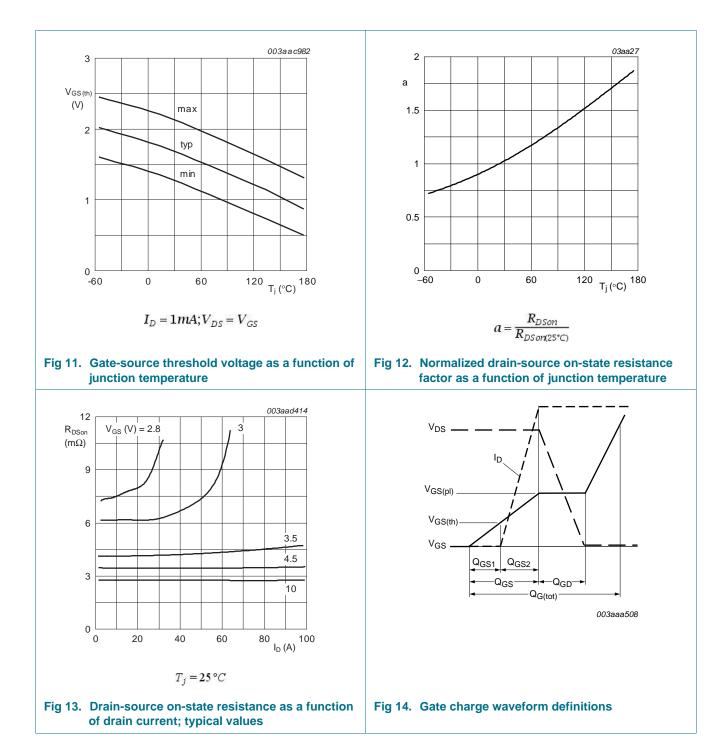
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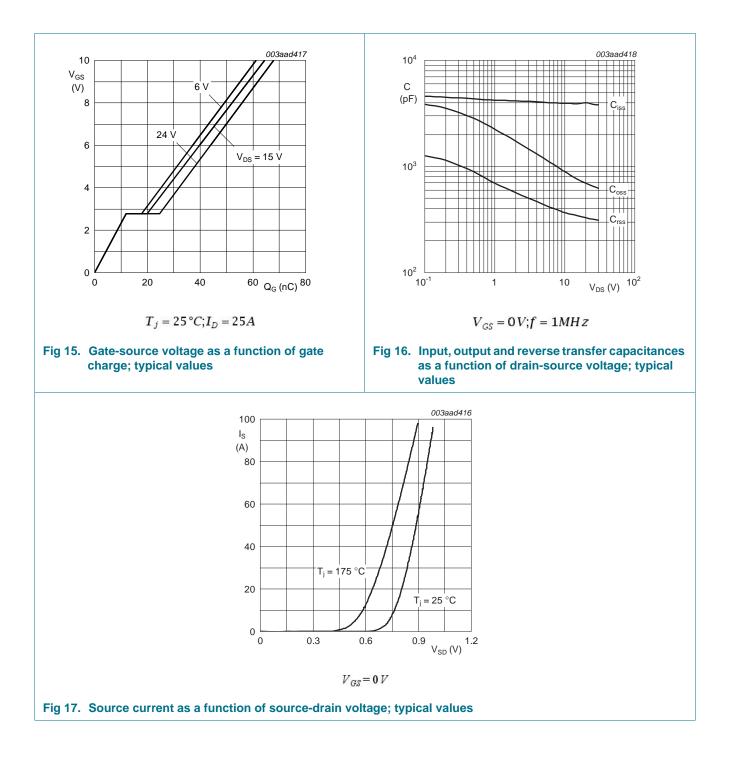
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8. Package outline

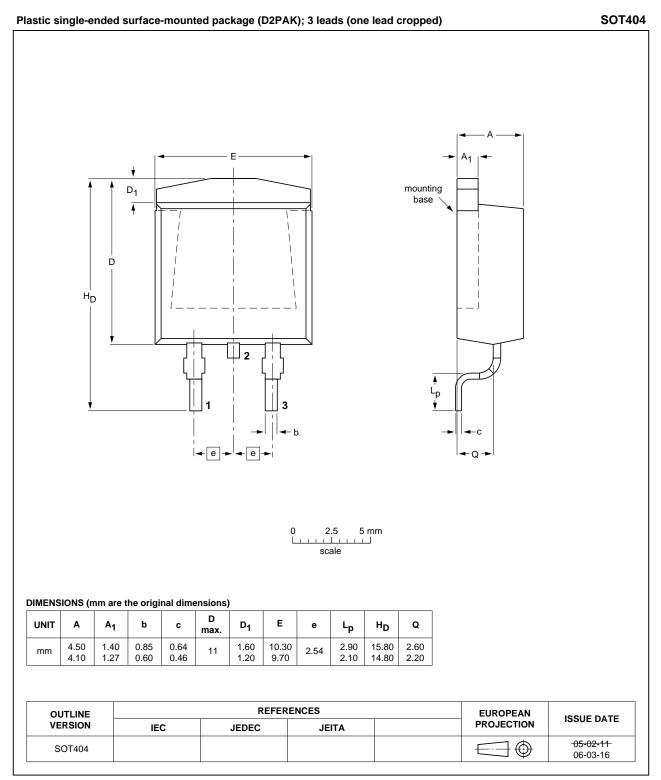


Fig 18. Package outline SOT404 (D2PAK)

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9. Revision history

Table 8. Revision h	8. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
PSMN3R4-30BL v.1	20120322	Product data sheet	-	-			

10. Legal information

10.1 Data sheet status

Document status[1] [2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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